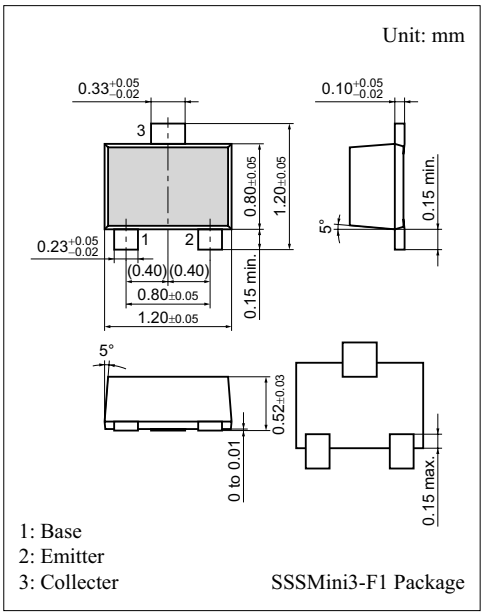
2SA2162

Silicon PNP epitaxial planar type

For general amplification
Complementary to 2SC6036

■ Features

- Low collector-emitter saturation voltage $V_{CE(sat)}$
- SSS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing



Marking Symbol : 2U

■ Absolute Maximum Ratings $T_a = 25°C$

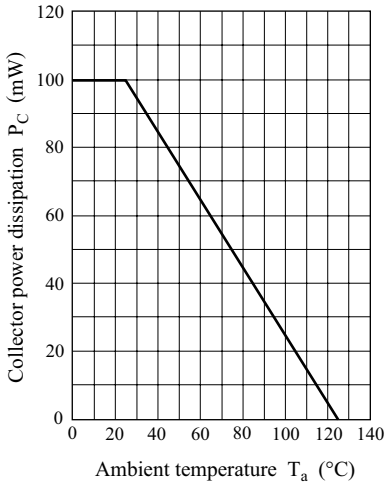
Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	–15	V
Collector-emitter voltage (Base open)	V_{CEO}	–12	V
Emitter-base voltage (Collector open)	V_{EBO}	–5	V
Collector current	I_C	–500	mA
Peak collector current	I_{CP}	–1	A
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	–55 to +125	°C

■ Electrical Characteristics $T_a = 25°C \pm 3°C$

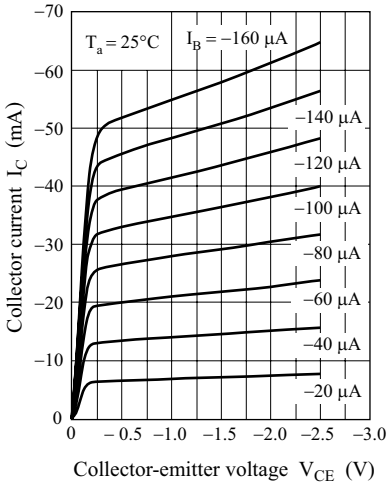
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = –10$ μA, $I_E = 0$	–15			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = –1$ mA, $I_B = 0$	–12			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = –10$ μA, $I_C = 0$	–5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = –10$ V, $I_E = 0$			– 0.1	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = –2$ V, $I_C = –10$ mA	270		680	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = –200$ mA, $I_B = –10$ mA			–250	mV
Transition frequency	f_T	$V_{CB} = –2$ V, $I_E = 10$ mA, f = 200 MHz		200		MHz
Collector output capacitance (Common base, input open circuited)	C_{ob}	$V_{CB} = –10$ V, f = 1 MHz		4.5		pF

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

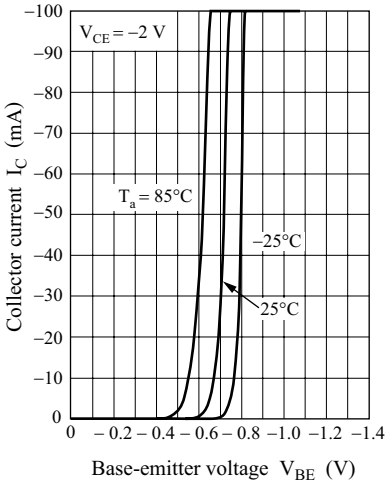
P_C — T_a



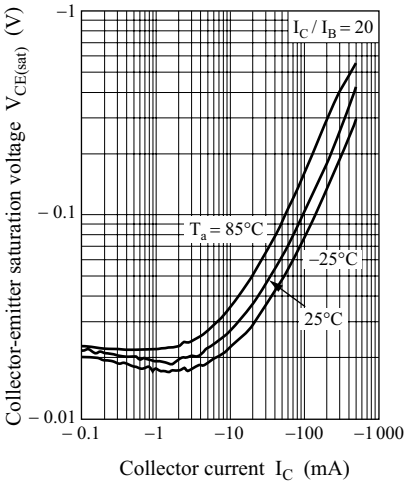
I_C — V_{CE}



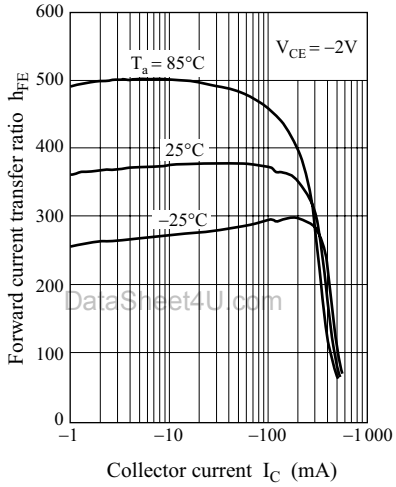
I_C — V_{BE}



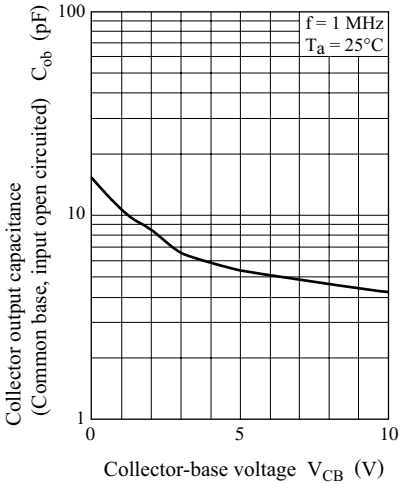
$V_{CE(sat)}$ — I_C



h_{FE} — I_C



C_{ob} — V_{CB}



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